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STMicroelectronics 2STA1943

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## High power PNP epitaxial planar bipolar transistor

### Features

- High breakdown voltage V<sub>CEO</sub> > -230V
- Complementary to 2STC5200
- Fast-switching speed
- Typical f<sub>T</sub> = 30 MHz

## Application

Audio power amplifier

### Description

This device is a NPN transistor manufactured using new BiT-LA (Bipolar Transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

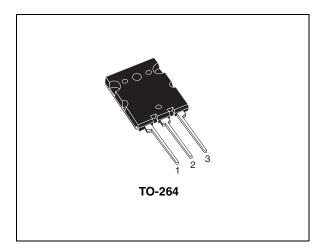
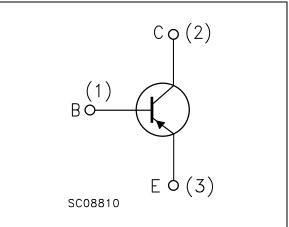


Figure 1. Internal schematic diagram



#### Table 1.Device summary

Order code	Marking	Package	Packaging
2STA1943	2STA1943	TO-264	Tube



#### **Electrical ratings**

2STA1943

## 1 Electrical ratings

#### Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	-230	V
V <sub>CEO</sub>	Collector-emitter voltage $(I_B = 0)$	-230	V
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0)$	-5	V
۱ <sub>C</sub>	Collector current	-15	А
I <sub>CM</sub>	Collector peak current	-30	А
P <sub>tot</sub>	Total dissipation at $T_{C} = 25^{\circ}C$	150	W
T <sub>stg</sub>	Storage temperature	-55 to 150	°C
TJ	Operating junction temperature	150	°C

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJ-case</sub>	Thermal resistance junction-case Max	0.83	°C/W



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## 2 Electrical characteristics

( $T_{case} = 25^{\circ}C$  unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -230 V			-5	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V			-5	μA
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage ( $I_B = 0$ )	I <sub>C</sub> = -50 mA	-230			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = -100 μΑ	-230			V
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> =-1 mA	-5			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -8 A I <sub>B</sub> = -800 mA			-3	V
$V_{BE}$	Base-emitter voltage	$I_{C} = -7 A$ $V_{CE} = -5 V$			-1.5	v
h <sub>FE</sub>	DC current gain	$I_{C} = -1 A$ $V_{CE} = -5 V$ $I_{C} = -7 A$ $V_{CE} = -5 V$	80 35		160	
t <sub>on</sub> t <sub>s</sub> t <sub>f</sub>	Resistive load Turn-on time Storage time Fall time	$V_{CC} = -60 V I_{C} = -5A$ $I_{B1} = -I_{B2} = -0.5 A$		0.24 1.2 0.21		μs μs μs
f <sub>T</sub>	Transition frequency	$I_{C} = -1 A$ $V_{CE} = -5 V$		30		MHz
C <sub>CBO</sub>	Collector-base capacitance (I <sub>E</sub> = 0)	V <sub>CB</sub> = -10 V f = 1 MHz		225		pF

#### Table 4. Electrical characteristics

1. Pulsed: pulse duration = 300  $\mu$ s, duty cycle  $\leq 1.5\%$ 

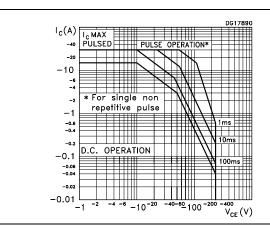


#### **Electrical characteristics**

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### 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area



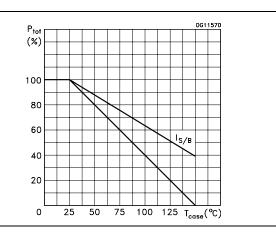


Figure 4. Output characteristics

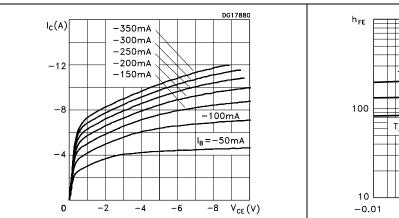


Figure 5. DC current gain

Figure 3. Derating curve

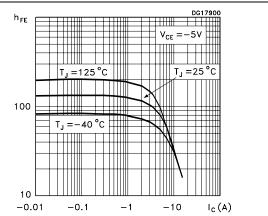
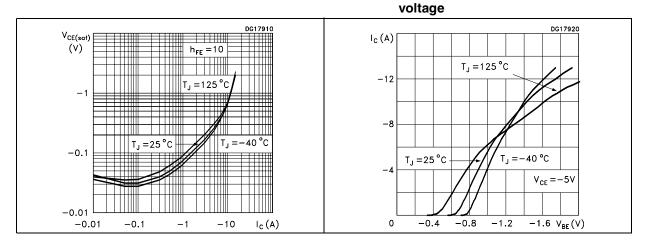


Figure 6. Collector-emitter saturation voltage Figure 7. Collector current vs base-emitter

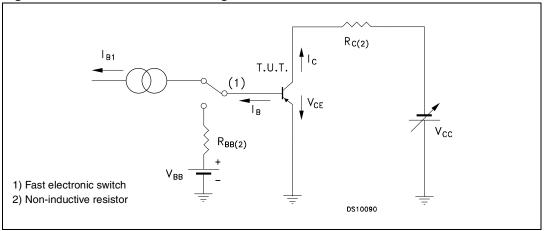






### 2.2 Test circuit

#### Figure 8. Resistive load switching test circuit







#### Package mechanical data

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## 3 Package mechanical data

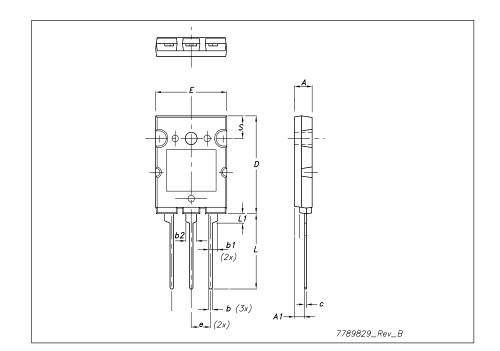
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Package mechanical data

	TO-264 Mechanical data		
Dim.		mm.	
	Min.	Тур	Max.
A	4.80		5.20
A1	2.50		3.10
b	0.90	1.0	1.25
b1		2.5	
b2		2.8	
С	0.50	0.60	0.85
D	25.6		26.4
E	19.80		20.20
е	5.15		5.75
L	19.50		20.50
L1	2.30		2.70
øP	3.55		3.65







#### **Revision history**

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## 4 **Revision history**

#### Table 5. Document revision history

Date	Revision	Changes
18-Jun-2007	1	Initial release.
12-Dec-2007	2	Document promoted from preliminary data to datasheet.





**Revision history** 

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